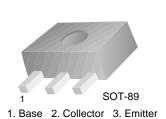


July 2007

FJC790 PNP Epitaxial Silicon Transistor

Camera Strobe Flash Application

- Complement to FJC690
- High Collector Current
- · Low Collector-Emitter Saturation Voltage



Marking 7 9 0 Weekly code Year code

Absolute Maximum Ratings * Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-40	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current (DC)	-2	А
P _C	Power Dissipation	0.5	W
T_J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics * T_a = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{mA}, I_B = 0$	-40			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -100 \mu A, I_C = 0$	-5			V
I _{CEO}	Collector Cut-off Current	$V_{CE} = -35V, V_{B} = 0$			-0.1	μА
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -4V, I_{C} = 0$			-0.1	μА
h _{FE}	DC Current Gain	$V_{CE} = -2V, I_{C} = -10 \text{mA}$ $V_{CE} = -2V, I_{C} = -500 \text{mA}$ $V_{CE} = -2V, I_{C} = -1 \text{A}$ $V_{CE} = -2V, I_{C} = -2 \text{A}$	300 250 200 150		800	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -0.5A$, $I_B = -5mA$ $I_C = -1A$, $I_B = -10mA$ $I_C = -2A$, $I_B = -50mA$			-250 -350 -450	mV mV mV
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = -1A, I _B = -10mA			-0.9	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -2V, I_{C} = 1A$			-0.8	V
C _{OB}	Collector Output Capacitance	$V_{CB} = -10V, I_{E} = 0, f = 1MHz$		20		pF
Pulse Test: Pulse	Width ≤ 300μs, Duty Cycle ≤ 2.0%	•	•	•	•	•

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
790	FJC790	SOT-89	13"		4,000

Typical Performance Characteristics

Figure 1. DC current Gain

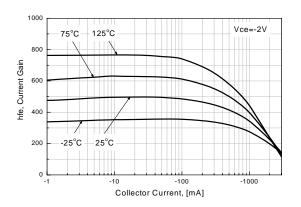


Figure 2. Collector-Base Capacitance

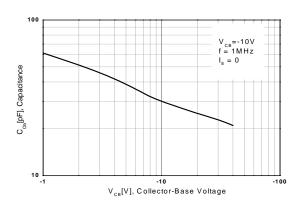


Figure 3. Collector-Emitter Saturation Voltage

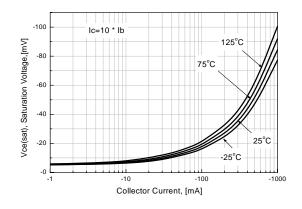


Figure 4. Collector-Emitter Saturation Voltage

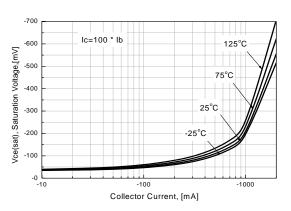


Figure 5. Base-Emitter Saturation Voltage

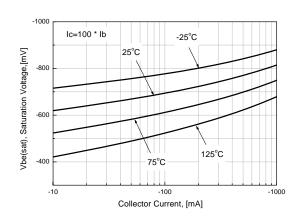
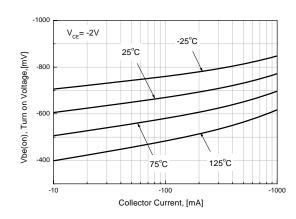
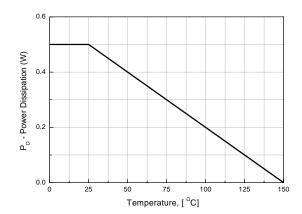


Figure 6. Base-Emitter Turn on Voltage



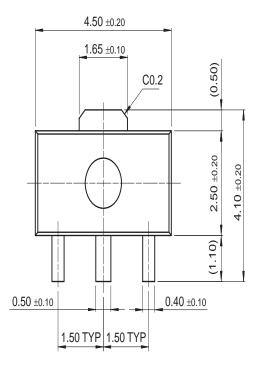
Typical Performance Characteristics

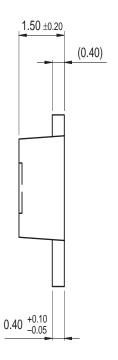
Figure 7. Power Dissipation vs
Ambient Temperature

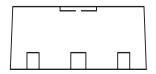


Mechanical Dimensions

SOT-89







Dimensions in Millimeters





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